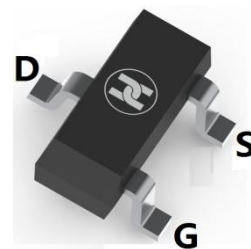


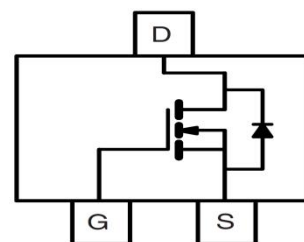
HIGH VOLTAGE MOSFET (N-CHANNEL)

FEATURES

- Low on-resistance: $V_{DS}=100V, R_{DS(ON)}=115m\Omega @ V_{GS}=10V, I_D=3A$
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Surface Mount device



SOT-23-3L



MECHANICAL DATA

- Case: SOT-23-3L
- Case Material: Molded Plastic. UL flammability
- Classification Rating: 94V-0
- Weight: 0.008 grams (approximate)
- Marking: 5N10

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V_{DS}	100	V
Gate-source voltage	V_{GS}	± 20	V
Continuous drain current	I_D	5	A
Pulsed drain current (Note 1)	I_{DM}	20	A
Power dissipation	P_D	3	W
Thermal resistance from Junction to ambient	$R_{\theta JA}$	42	$^\circ\text{C/W}$
Junction temperature	T_J	150	$^\circ\text{C}$
Storage temperature	T_{STG}	-55 ~ +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
STATIC CHARACTERISTICS						
Drain-Source breakdown voltage	$V_{(BR)DSS}$	100			V	$V_{GS}=0V, I_D=250\mu A$
Zero gate voltage drain current	I_{DSS}			1	μA	$V_{DS}=100V, V_{GS}=0V$
Gate-body leakage current	I_{GSS}			± 100	nA	$V_{DS}=0V, V_{GS}=\pm 20V$
Gate-threshold voltage (note 1)	$V_{GS(th)}$	1.2	1.8	2.5	V	$V_{DS}=V_{GS}, I_D=250\mu A$
Drain-source on-resistance (note 1)	$R_{DS(ON)}$		95	115	$m\Omega$	$V_{GS}=10V, I_D=3A$
			115	150	$m\Omega$	$V_{GS}=4.5V, I_D=3A$
Diode forward voltage (note 1)	V_{SD}		0.7	1.2	V	$I_S=3A, V_{GS}=0V$
DYNAMIC CHARACTERISTICS						
Input capacitance	C_{iss}		690		pF	$V_{DS}=25V, V_{GS}=0V, f=1MHz$
Output capacitance	C_{oss}		120		pF	
Reverse transfer capacitance	C_{rss}		90		pF	
Gate Resistance	R_g		2		Ω	$V_{DS}=0V, V_{GS}=0V, f=1MHz$
Total gate charge	Q_g		5		nC	$V_{DD}=30V, V_{GS}=4.5V, I_D=3A$
			15.5		nC	
Gate-source charge	Q_{gs}		3.2		nC	$V_{DD}=30V, V_{GS}=10V, I_D=3A$
Gate-drain charge	Q_{gd}		4.7		nC	
Turn-on delay time	$t_{d(on)}$		11		nS	$V_{DS}=30V, V_{GS}=10V, R_{GEN}=2.5\Omega, I_D=2A$
Turn-on rise time	t_r		8		nS	
Turn-off delay time	$t_{d(off)}$		35		nS	
Turn-off fall time	t_f		9		nS	

Note:1. Pulse test ; Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$.

HIGH VOLTAGE MOSFET (N-CHANNEL) Typical Characteristics

Figure1. Source-Drain Diode Forward Voltage

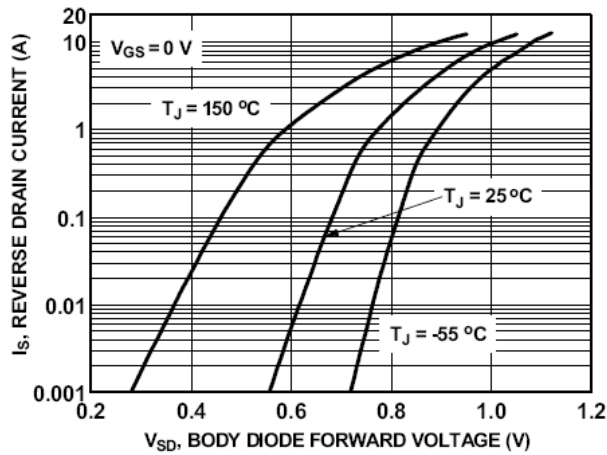


Figure2. Safe operating area

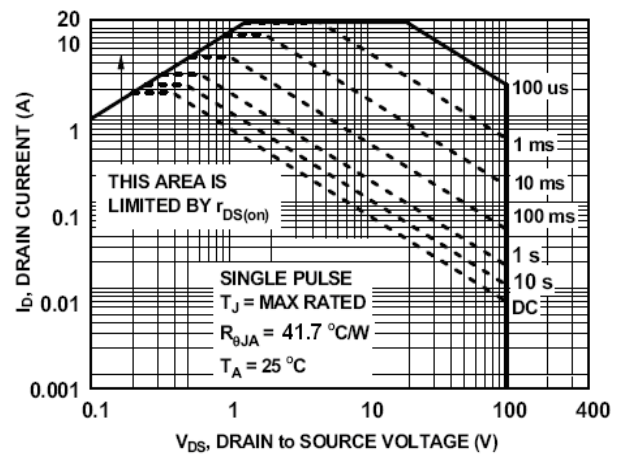


Figure3. Output characteristics

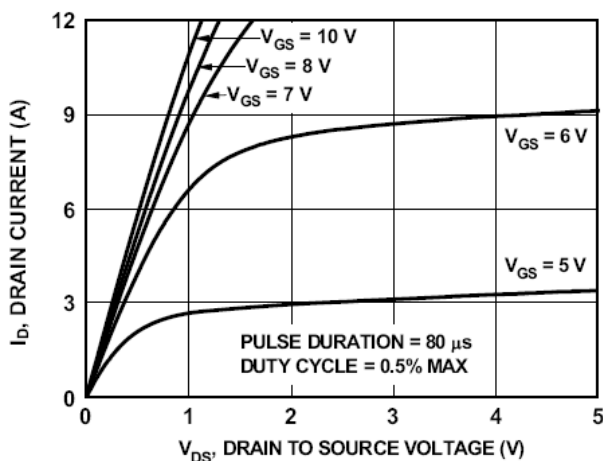


Figure4. Transfer characteristics

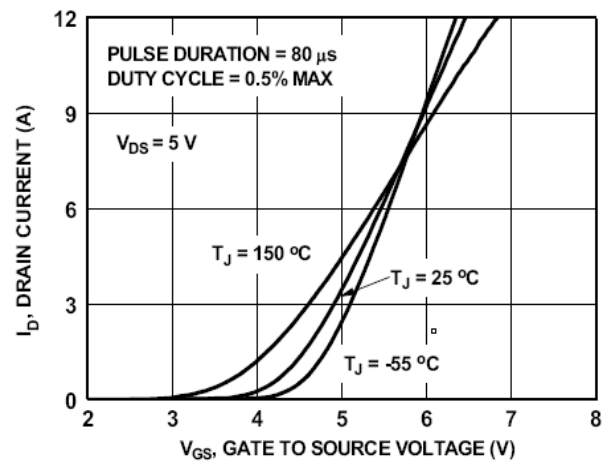


Figure5. Static drain-source on resistance

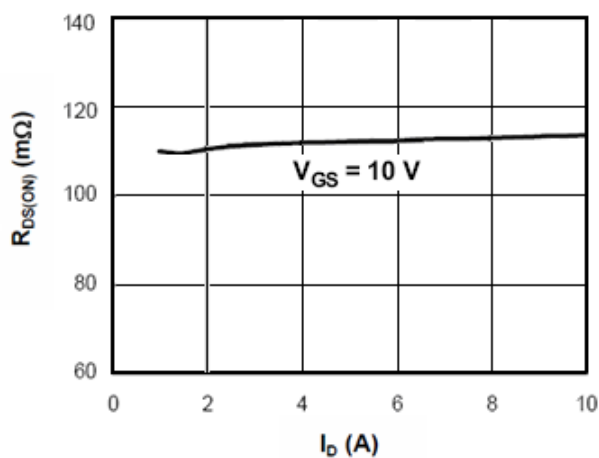
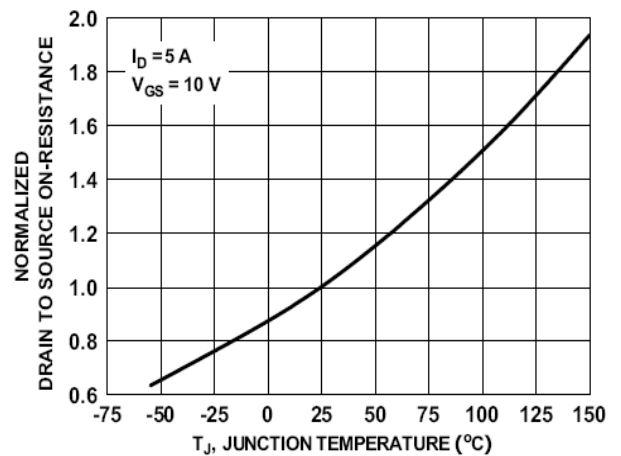


Figure6. $R_{DS(ON)}$ vs Junction Temperature



HIGH VOLTAGE MOSFET (N-CHANNEL)

Figure7. BV_{DSS} vs Junction Temperature

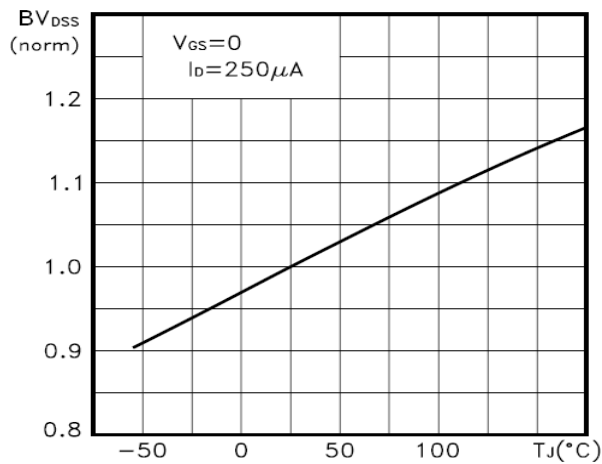


Figure8. $V_{GS(th)}$ vs Junction Temperature

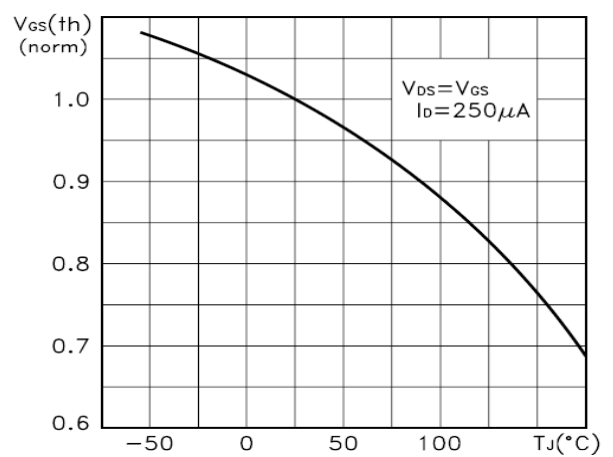


Figure9. Gate charge waveforms

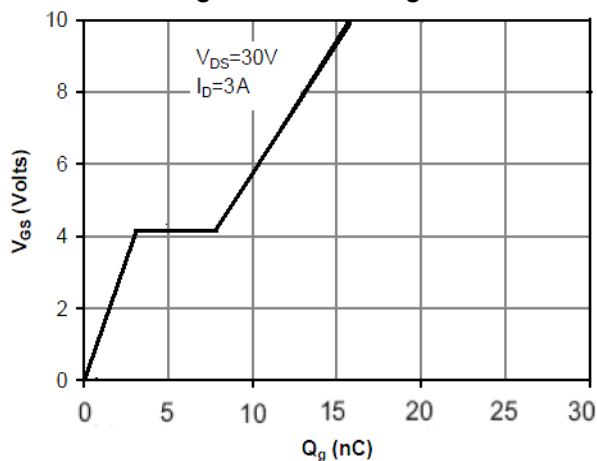


Figure10. Capacitance

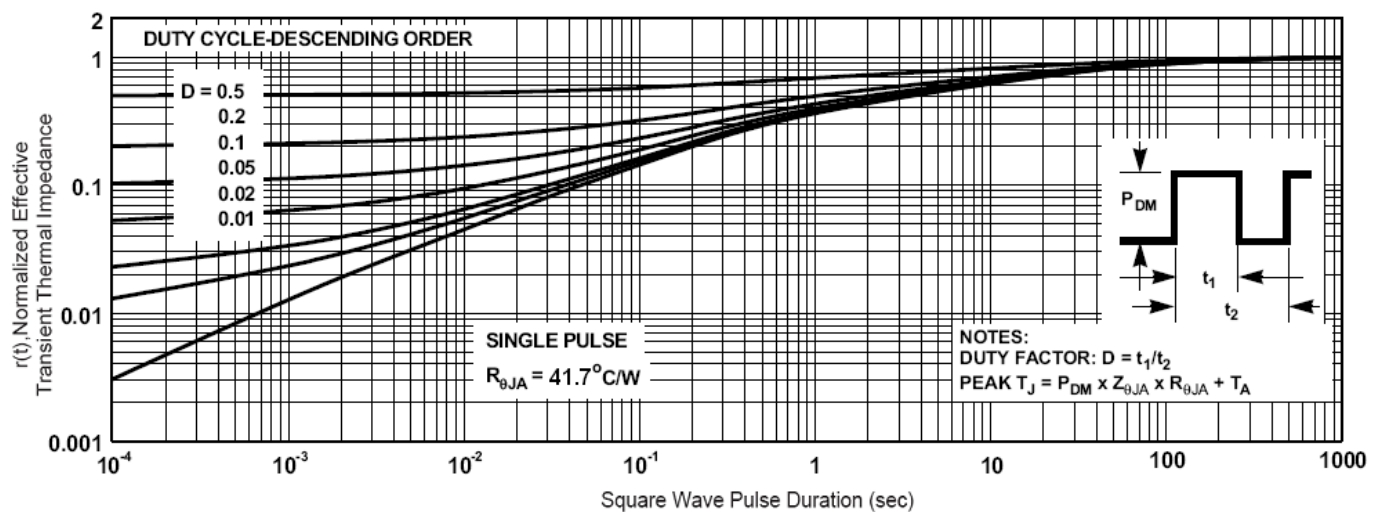
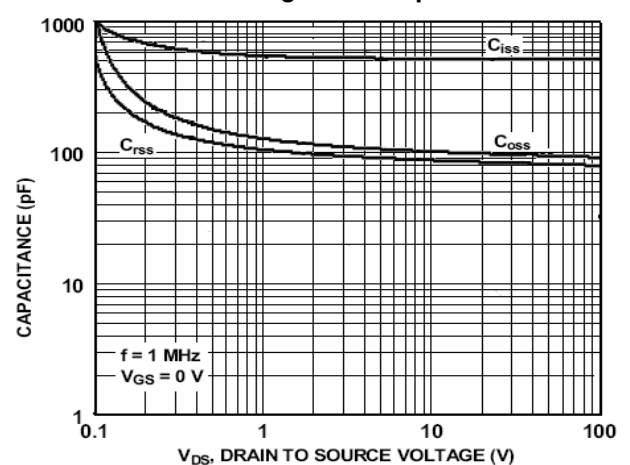
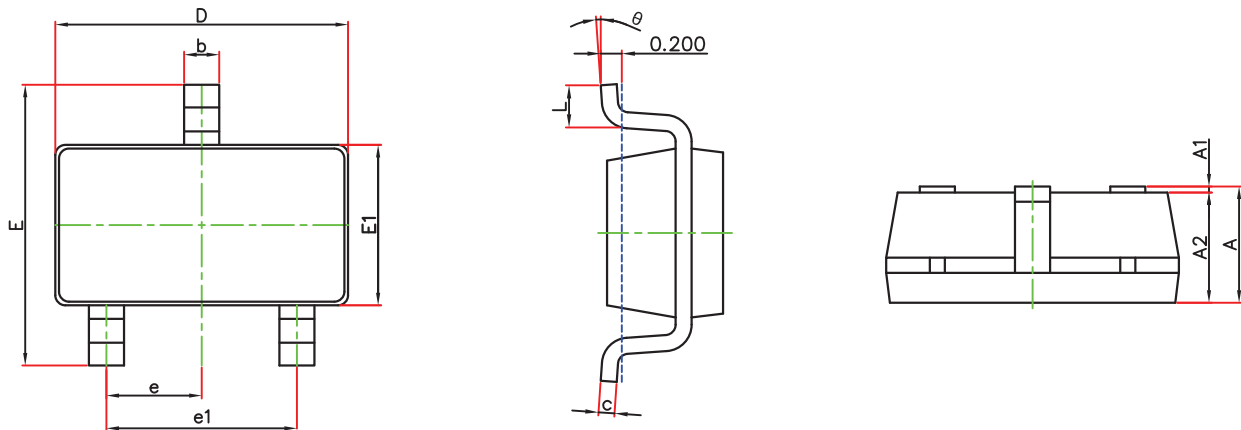


Figure11. Normalized Maximum Transient Thermal Impedance

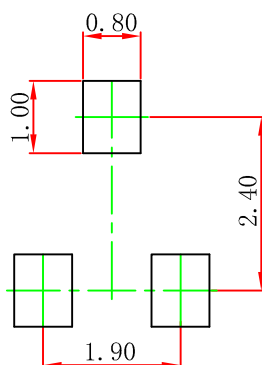
HIGH VOLTAGE MOSFET (N-CHANNEL)

SOT-23-3L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

SOT-23-3L Suggested Pad Layout



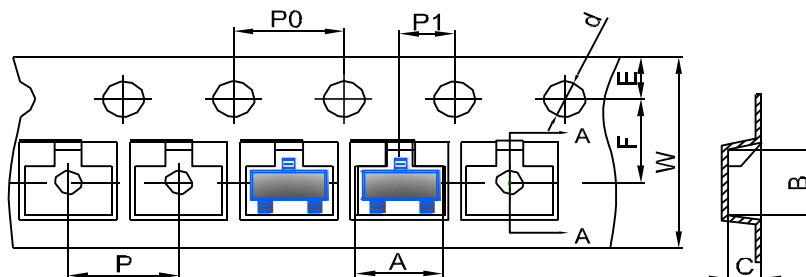
Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

HIGH VOLTAGE MOSFET (N-CHANNEL)

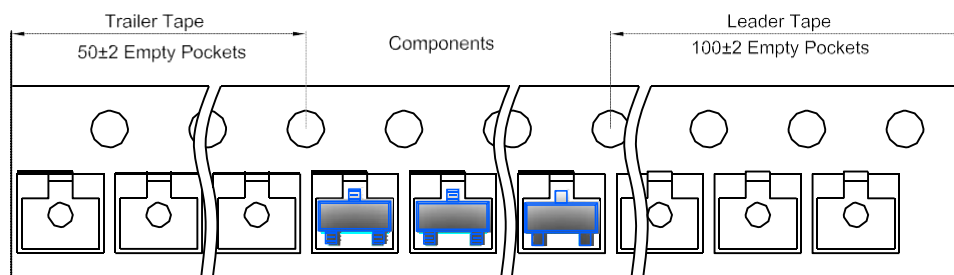
SOT-23-3L Tape and Reel

SOT-23-3L Embossed Carrier Tape

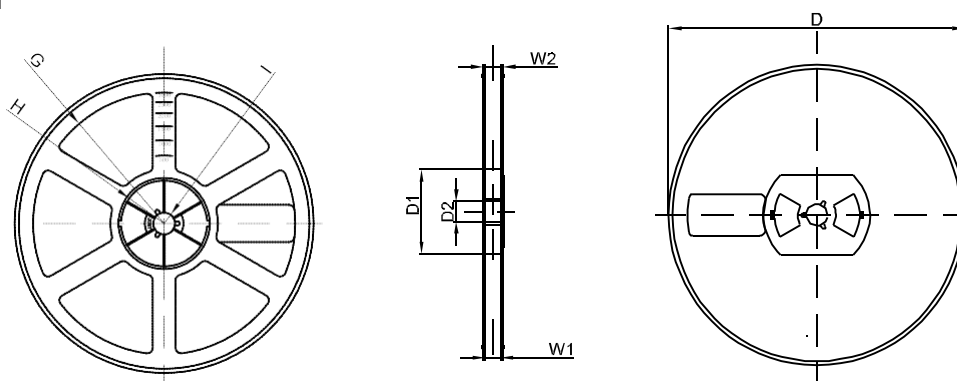


DIMENSIONS ARE IN MILLIMETER										
TYPE	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

SOT-23-3L Tape Leader and Trailer



SOT-23-3L Reel



DIMENSIONS ARE IN MILLIMETER								
REEL OPTION	D	D1	D2	G	H	I	W1	W2
7" DIA	Ø178	54.40	13.00	R78	R25.60	R6.50	9.50	12.30
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1